

FEATURES

True single-supply operation

Output swings rail-to-rail

Input voltage range extends below ground

Single-supply capability from 5 V to 30 V

Dual-supply capability from ± 2.5 V to ± 15 V

High load drive

Capacitive load drive of 350 pF, $G = +1$

Minimum output current of 15 mA

Excellent ac performance for low power

800 μ A maximum quiescent current per amplifier

Unity-gain bandwidth: 1.8 MHz

Slew rate of 3 V/ μ s

Good dc performance

800 μ V maximum input offset voltage

2 μ V/ $^{\circ}$ C typical offset voltage drift

25 pA maximum input bias current

Low noise

13 nV/ $\sqrt{\text{Hz}}$ at 10 kHz

No phase inversion

APPLICATIONS

Battery-powered precision instrumentation

Photodiode preamps

Active filters

12-bit to 14-bit data acquisition systems

Medical instrumentation

Low power references and regulators

GENERAL DESCRIPTION

The **AD822** is a dual precision, low power FET input op amp that can operate from a single supply of 5 V to 30 V or from dual supplies of ± 2.5 V to ± 15 V. It has true single-supply capability with an input voltage range extending below the negative rail, allowing the **AD822** to accommodate input signals below ground while in the single-supply mode. Output voltage swing extends to within 10 mV of each rail, providing the maximum output dynamic range.

Offset voltage of 800 μ V maximum, offset voltage drift of 2 μ V/ $^{\circ}$ C, input bias currents below 25 pA, and low input voltage noise provide dc precision with source impedances up to a gigaohm. The 1.8 MHz unity-gain bandwidth, -93 dB total harmonic distortion (THD) at 10 kHz, and 3 V/ μ s slew rate are provided with a low supply current of 800 μ A per amplifier.

CONNECTION DIAGRAM

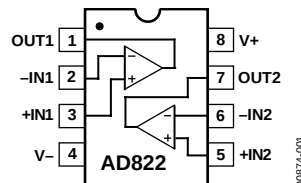


Figure 1. 8-Lead PDIP (N Suffix);
8-Lead MSOP (RM Suffix);
and 8-Lead SOIC_N (R Suffix)

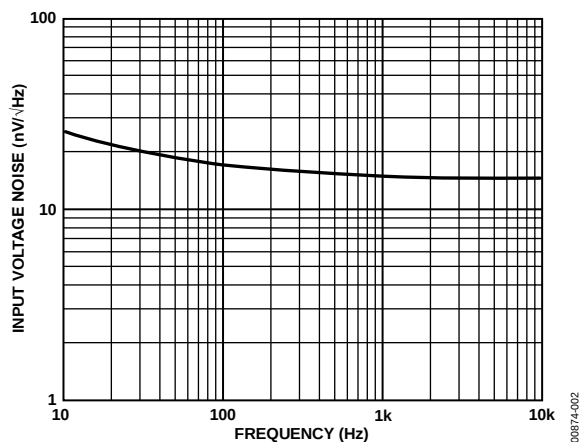


Figure 2. Input Voltage Noise vs. Frequency

Rev. J

[Document Feedback](#)

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A.
Tel: 781.329.4700 ©1993–2015 Analog Devices, Inc. All rights reserved.
[Technical Support](#) www.analog.com

TABLE OF CONTENTS

Features	1
Applications	1
Connection Diagram	1
General Description	1
Revision History	2
Specifications	4
Absolute Maximum Ratings	10
Thermal Resistance	10
Maximum Power Dissipation	10
ESD Caution	10

REVISION HISTORY

9/15—Rev. I to Rev. J

Changes to Figure 12	12
----------------------------	----

1/10—Rev. H to Rev. I

Changes to Features Section and General Description Section .	1
Changes to Endnote 1, Table 1	5
Changes to Endnote 1, Table 2	7
Changes to Endnote 1, Table 3	9
Deleted Table 4; Renumbered Sequentially	10
Changes to Table 5	12
Updated Outline Dimensions	21
Changes to Ordering Guide	22
Deleted 3 V, Single-Supply Stereo Headphone Driver Section.	22
Deleted Figure 50; Renumbered Sequentially	22

8/08—Rev. G to Rev. H.

Changes to Features Section and General Description Section .	1
Changed V_O to V_{OUT} Throughout	4
Changes to Table 1	4
Changes to Table 2	6
Changes to Table 3	8
Changes to Table 5	12
Added Table 6; Renumbered Sequentially	12
Changes to Figure 13 Caption	14
Changes to Figure 29, Figure 31, and Figure 35	17
Changes to Figure 36	18
Changed Application Notes Section to Applications	
Information Section	20
Changes to Figure 46 and Figure 47	21
Changes to Figure 49	22
Changes to Figure 51	23

6/06—Rev. F to Rev. G

Changes to Features	1
Changes to Table 4	10
Changes to Table 5	12
Changes to Table 6	22

Typical Performance Characteristics	11
Applications Information	18
Input Characteristics	18
Output Characteristics	18
Single-Supply Voltage to Frequency Converter	19
Single-Supply Programmable Gain Instrumentation	
Amplifier	20
Low Dropout Bipolar Bridge Driver	20
Outline Dimensions	21
Ordering Guide	22

10/05—Rev. E to Rev. F

Updated Format	Universal
Changes to Outline Dimensions	24
Updated Ordering Guide	24

1/03—Rev. D to Rev. E

Edits to Specifications	2
Edits to Figure 10	16
Updated Outline Dimensions	17

10/02—Rev. C to Rev. D

Edits to Features	1
Edits to Ordering Guide	6
Updated SOIC Package Outline	17

8/02—Rev. B to Rev. C

All Figures Updated	Universal
Edits to Features	1
Updated All Package Outlines	17

7/01—Rev. A to Rev. B

All Figures Updated	Universal
CERDIP References Removed	1, 6, and 18
Additions to Product Description	1
8-Lead SOIC and 8-Lead MSOP Diagrams Added	1
Deletion of AD822S Column	2
Edits to Absolute Maximum Ratings and Ordering Guide	6
Removed Metallization Photograph	6

7/93—Revision 0: Initial Version

The AD822 drives up to 350 pF of direct capacitive load as a follower and provides a minimum output current of 15 mA. This allows the amplifier to handle a wide range of load conditions. Its combination of ac and dc performance, plus the outstanding load drive capability, results in an exceptionally versatile amplifier for the single-supply user.

The AD822 is available in two performance grades. The A grade and B grade are rated over the industrial temperature range of -40°C to $+85^{\circ}\text{C}$.

The AD822 is offered in three varieties of 8-lead packages: PDIP, MSOP, and SOIC_N.

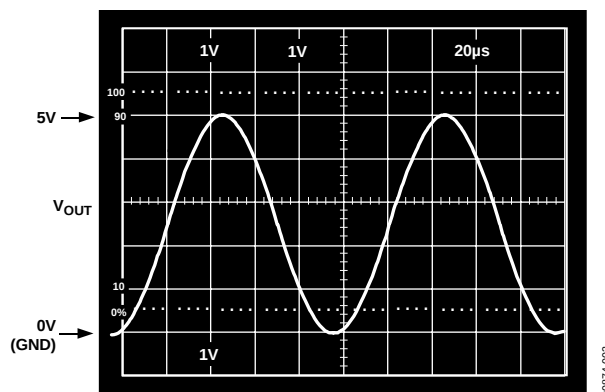


Figure 3. Gain of 2 Amplifier; $V_S = 5\text{ V}$, 0 V , $V_{IN} = 2.5\text{ V}$ Sine Centered at 1.25 V , $R_L = 100\ \Omega$

SPECIFICATIONS

$V_S = 0\text{ V}$, 5 V at $T_A = 25^\circ\text{C}$, $V_{CM} = 0\text{ V}$, $V_{OUT} = 0.2\text{ V}$, unless otherwise noted.

Table 1.

Parameter	Test Conditions/Comments	Min	A Grade Typ	Max	Min	B Grade Typ	Max	Unit	
DC PERFORMANCE									
Initial Offset	V _{CM} = 0 V to 4 V		0.1	0.8		0.1	0.4	mV	
Maximum Offset Over Temperature			0.5	1.2		0.5	0.9	mV	
Offset Drift			2			2		μV/°C	
Input Bias Current			2	25		2	10	pA	
At T _{MAX}			0.5	5		0.5	2.5	nA	
Input Offset Current			2	20		2	10	pA	
At T _{MAX}			0.5			0.5		nA	
Open-Loop Gain	V _{OUT} = 0.2 V to 4 V								
	R _L = 100 kΩ	500	1000		500	1000		V/mV	
T _{MIN} to T _{MAX}		400			400			V/mV	
	R _L = 10 kΩ	80	150		80	150		V/mV	
T _{MIN} to T _{MAX}		80			80			V/mV	
	R _L = 1 kΩ	15	30		15	30		V/mV	
T _{MIN} to T _{MAX}		10			10			V/mV	
NOISE/HARMONIC PERFORMANCE									
Input Voltage Noise	R _L = 10 kΩ to 2.5 V V _{OUT} = 0.25 V to 4.75 V								
f = 0.1 Hz to 10 Hz			2			2		μV p-p	
f = 10 Hz			25			25		nV/√Hz	
f = 100 Hz			21			21		nV/√Hz	
f = 1 kHz			16			16		nV/√Hz	
f = 10 kHz			13			13		nV/√Hz	
Input Current Noise									
f = 0.1 Hz to 10 Hz				18			18		fA p-p
f = 1 kHz				0.8			0.8		fA/√Hz
Harmonic Distortion									
f = 10 kHz				−93			−93		dB
DYNAMIC PERFORMANCE									
Unity-Gain Frequency	V _{OUT} p-p = 4.5 V		1.8			1.8		MHz	
Full Power Response			210			210		kHz	
Slew Rate			3			3		V/μs	
Settling Time	V _{OUT} = 0.2 V to 4.5 V								
To 0.1%			1.4			1.4		μs	
To 0.01%	V _{OUT} = 0.2 V to 4.5 V		1.8			1.8		μs	
MATCHING CHARACTERISTICS									
Initial Offset	R _L = 5 kΩ			1.0			0.5	mV	
Maximum Offset Over Temperature				1.6			1.3	mV	
Offset Drift			3			3		μV/°C	
Input Bias Current				20			10	pA	
Crosstalk @ f = 1 kHz			−130			−130		dB	
Crosstalk @ f = 100 kHz			−93			−93		dB	

Parameter	Test Conditions/Comments	A Grade			B Grade			Unit
		Min	Typ	Max	Min	Typ	Max	
INPUT CHARACTERISTICS								
Input Voltage Range ¹ , T _{MIN} to T _{MAX}	V _{CM} = 0 V to 2 V	−0.2		+4	−0.2		+4	V
Common-Mode Rejection Ratio (CMRR) T _{MIN} to T _{MAX}		66	80		69	80		dB
Input Impedance Differential		66			66			dB
Common Mode			10 ¹³ 0.5			10 ¹³ 0.5		Ω pF
				10 ¹³ 2.8			10 ¹³ 2.8	Ω pF
OUTPUT CHARACTERISTICS								
Output Saturation Voltage ² V _{OL} − V _{EE} T _{MIN} to T _{MAX}	I _{SINK} = 20 μA		5	7		5	7	mV
V _{CC} − V _{OH} T _{MIN} to T _{MAX}				10			10	mV
V _{OL} − V _{EE} T _{MIN} to T _{MAX}	I _{SOURCE} = 20 μA		10	14		10	14	mV
V _{CC} − V _{OH} T _{MIN} to T _{MAX}				20			20	mV
V _{OL} − V _{EE} T _{MIN} to T _{MAX}	I _{SINK} = 2 mA		40	55		40	55	mV
V _{CC} − V _{OH} T _{MIN} to T _{MAX}				80			80	mV
V _{OL} − V _{EE} T _{MIN} to T _{MAX}	I _{SOURCE} = 2 mA		80	110		80	110	mV
V _{CC} − V _{OH} T _{MIN} to T _{MAX}				160			160	mV
V _{OL} − V _{EE} T _{MIN} to T _{MAX}	I _{SINK} = 15 mA		300	500		300	500	mV
V _{CC} − V _{OH} T _{MIN} to T _{MAX}				1000			1000	mV
V _{OL} − V _{EE} T _{MIN} to T _{MAX}	I _{SOURCE} = 15 mA		800	1500		800	1500	mV
V _{CC} − V _{OH} T _{MIN} to T _{MAX}				1900			1900	mV
Operating Output Current T _{MIN} to T _{MAX}		15			15			mA
Capacitive Load Drive		12			12			mA
			350			350		pF
POWER SUPPLY								
Quiescent Current, T _{MIN} to T _{MAX}	V+ = 5 V to 15 V		1.24	1.6		1.24	1.6	mA
Power Supply Rejection T _{MIN} to T _{MAX}		66	80		70	80		dB
		66			70			dB

¹ This is a functional specification. Amplifier bandwidth decreases when the input common-mode voltage is driven in the range $(V_{+} - 1\text{ V})$ to V_{+} . Common-mode error voltage is typically less than 5 mV with the common-mode voltage set at 1 V below the positive supply.

² $V_{OL} - V_{EE}$ is defined as the difference between the lowest possible output voltage (V_{OL}) and the negative voltage supply rail (V_{EE}). $V_{CC} - V_{OH}$ is defined as the difference between the highest possible output voltage (V_{OH}) and the positive supply voltage (V_{CC}).

$V_S = \pm 5\text{ V}$ at $T_A = 25^\circ\text{C}$, $V_{CM} = 0\text{ V}$, $V_{OUT} = 0\text{ V}$, unless otherwise noted.

Table 2.

Parameter	Test Conditions/Comments	A Grade			B Grade			Unit
		Min	Typ	Max	Min	Typ	Max	
DC PERFORMANCE								
Initial Offset	V _{CM} = −5 V to +4 V		0.1	0.8		0.1	0.4	mV
Maximum Offset Over Temperature			0.5	1.5		0.5	1	mV
Offset Drift			2			2		μV/°C
Input Bias Current			2	25		2	10	pA
At T _{MAX}			0.5	5		0.5	2.5	nA
Input Offset Current			2	20		2	10	pA
At T _{MAX}			0.5			0.5		nA
Open-Loop Gain	V _{OUT} = −4 V to +4 V							
	R _L = 100 kΩ	400	1000		400	1000		V/mV
T _{MIN} to T _{MAX}		400			400			V/mV
	R _L = 10 kΩ	80	150		80	150		V/mV
T _{MIN} to T _{MAX}		80			80			V/mV
	R _L = 1 kΩ	20	30		20	30		V/mV
T _{MIN} to T _{MAX}		10			10			V/mV
NOISE/HARMONIC PERFORMANCE								
Input Voltage Noise	R _L = 10 kΩ							
f = 0.1 Hz to 10 Hz			2			2		μV p-p
f = 10 Hz			25			25		nV/√Hz
f = 100 Hz			21			21		nV/√Hz
f = 1 kHz			16			16		nV/√Hz
f = 10 kHz			13			13		nV/√Hz
Input Current Noise								
f = 0.1 Hz to 10 Hz				18			18	fA p-p
f = 1 kHz				0.8			0.8	fA/√Hz
Harmonic Distortion		V _{OUT} = ±4.5 V						
f = 10 kHz			−93			−93		dB
DYNAMIC PERFORMANCE								
Unity-Gain Frequency	V _{OUT} p-p = 9 V		1.9			1.9		MHz
Full Power Response			105			105		kHz
Slew Rate			3			3		V/μs
Settling Time	V _{OUT} = 0 V to ±4.5 V							
to 0.1%			1.4			1.4		μs
to 0.01%	V _{OUT} = 0 V to ±4.5 V		1.8			1.8		μs
MATCHING CHARACTERISTICS								
Initial Offset	R _L = 5 kΩ			1.0			0.5	mV
Maximum Offset Over Temperature				3			2	mV
Offset Drift			3			3		μV/°C
Input Bias Current				25			10	pA
Crosstalk @ f = 1 kHz			−130			−130		dB
Crosstalk @ f = 100 kHz			−93			−93		dB
INPUT CHARACTERISTICS								
Input Voltage Range ¹ , T _{MIN} to T _{MAX}	V _{CM} = −5 V to +2 V	−5.2		+4	−5.2		+4	V
Common-Mode Rejection Ratio (CMRR)		66	80		69	80		dB
T _{MIN} to T _{MAX}		66			66			dB
Input Impedance								
Differential				10 ¹³ 0.5			10 ¹³ 0.5	Ω pF
Common Mode			10 ¹³ 2.8			10 ¹³ 2.8	Ω pF	

Parameter	Test Conditions/Comments	A Grade			B Grade			Unit
		Min	Typ	Max	Min	Typ	Max	
OUTPUT CHARACTERISTICS								
Output Saturation Voltage ²								
$V_{OL} - V_{EE}$ T_{MIN} to T_{MAX}	$I_{SINK} = 20\ \mu A$		5	7		5	7	mV
$V_{CC} - V_{OH}$ T_{MIN} to T_{MAX}	$I_{SOURCE} = 20\ \mu A$		10	14		10	14	mV
$V_{OL} - V_{EE}$ T_{MIN} to T_{MAX}	$I_{SINK} = 2\ mA$		40	55		40	55	mV
$V_{CC} - V_{OH}$ T_{MIN} to T_{MAX}	$I_{SOURCE} = 2\ mA$		80	110		80	110	mV
$V_{OL} - V_{EE}$ T_{MIN} to T_{MAX}	$I_{SINK} = 15\ mA$		300	500		300	500	mV
$V_{CC} - V_{OH}$ T_{MIN} to T_{MAX}	$I_{SOURCE} = 15\ mA$		800	1500		800	1500	mV
Operating Output Current T_{MIN} to T_{MAX}		15			15			mA
Capacitive Load Drive		12			12			mA
			350			350		pF
POWER SUPPLY								
Quiescent Current, T_{MIN} to T_{MAX}			1.3	1.6		1.3	1.6	mA
Power Supply Rejection T_{MIN} to T_{MAX}	$V_{SY} = \pm 5\ V$ to $\pm 15\ V$	66	80		70	80		dB
		66			70			dB

¹ This is a functional specification. Amplifier bandwidth decreases when the input common-mode voltage is driven in the range ($V_{+} - 1 V$) to V_{+} . Common-mode error voltage is typically less than 5 mV with the common-mode voltage set at 1 V below the positive supply.

² $V_{OL} - V_{EE}$ is defined as the difference between the lowest possible output voltage (V_{OL}) and the negative voltage supply rail (V_{EE}). $V_{CC} - V_{OH}$ is defined as the difference between the highest possible output voltage (V_{OH}) and the positive supply voltage (V_{CC}).

$V_S = \pm 15\text{ V}$ at $T_A = 25^\circ\text{C}$, $V_{CM} = 0\text{ V}$, $V_{OUT} = 0\text{ V}$, unless otherwise noted.

Table 3.

Parameter	Test Conditions/Comments	A Grade			B Grade			Unit
		Min	Typ	Max	Min	Typ	Max	
DC PERFORMANCE								
Initial Offset			0.4	2		0.3	1.5	mV
Maximum Offset Over Temperature			0.5	3		0.5	2.5	mV
Offset Drift			2			2		μV/°C
Input Bias Current	V _{CM} = 0 V		2	25		2	12	pA
	V _{CM} = −10 V		40			40		pA
At T _{MAX}	V _{CM} = 0 V		0.5	5		0.5	2.5	nA
Input Offset Current			2	20		2	12	pA
At T _{MAX}			0.5			0.5		nA
Open-Loop Gain	V _{OUT} = −10 V to +10 V							
	R _L = 100 kΩ	500	2000		500	2000		V/mV
T _{MIN} to T _{MAX}		500			500			V/mV
	R _L = 10 kΩ	100	500		100	500		V/mV
T _{MIN} to T _{MAX}		100			100			V/mV
	R _L = 1 kΩ	30	45		30	45		V/mV
T _{MIN} to T _{MAX}		20			20			V/mV
NOISE/HARMONIC PERFORMANCE								
Input Voltage Noise								
f = 0.1 Hz to 10 Hz			2			2		μV p-p
f = 10 Hz			25			25		nV/√Hz
f = 100 Hz			21			21		nV/√Hz
f = 1 kHz			16			16		nV/√Hz
f = 10 kHz			13			13		nV/√Hz
Input Current Noise								
f = 0.1 Hz to 10 Hz			18			18		fA p-p
f = 1 kHz			0.8			0.8		fA/√Hz
Harmonic Distortion	R _L = 10 kΩ							
f = 10 kHz	V _{OUT} = ±10 V		−85			−85		dB
DYNAMIC PERFORMANCE								
Unity-Gain Frequency			1.9			1.9		MHz
Full Power Response	V _{OUT} p-p = 20 V		45			45		kHz
Slew Rate			3			3		V/μs
Settling Time								
to 0.1%	V _{OUT} = 0 V to ±10 V		4.1			4.1		μs
to 0.01%	V _{OUT} = 0 V to ±10 V		4.5			4.5		μs
MATCHING CHARACTERISTICS								
Initial Offset				3			2	mV
Maximum Offset Over Temperature				4			2.5	mV
Offset Drift			3			3		μV/°C
Input Bias Current				25			12	pA
Crosstalk @ f = 1 kHz	R _L = 5 kΩ		−130			−130		dB
Crosstalk @ f = 100 kHz	R _L = 5 kΩ		−93			−93		dB
INPUT CHARACTERISTICS								
Input Voltage Range ¹ , T _{MIN} to T _{MAX}		−15.2		+14	−15.2		+14	V
Common-Mode Rejection Ratio (CMRR)	V _{CM} = −15 V to +12 V	70	80		74	90		dB
T _{MIN} to T _{MAX}	V _{CM} = −15 V to +12 V	70			74			dB
Input Impedance								
Differential			10 ¹³ 0.5			10 ¹³ 0.5		Ω pF
Common Mode			10 ¹³ 2.8			10 ¹³ 2.8		Ω pF

Parameter	Test Conditions/Comments	A Grade			B Grade			Unit
		Min	Typ	Max	Min	Typ	Max	
OUTPUT CHARACTERISTICS								
Output Saturation Voltage ²								
$V_{OL} - V_{EE}$ T_{MIN} to T_{MAX}	$I_{SINK} = 20 \mu A$		5	7		5	7	mV
$V_{CC} - V_{OH}$ T_{MIN} to T_{MAX}	$I_{SOURCE} = 20 \mu A$		10	14		10	14	mV
$V_{OL} - V_{EE}$ T_{MIN} to T_{MAX}	$I_{SINK} = 2 \text{ mA}$		40	55		40	55	mV
$V_{CC} - V_{OH}$ T_{MIN} to T_{MAX}	$I_{SOURCE} = 2 \text{ mA}$		80	110		80	110	mV
$V_{OL} - V_{EE}$ T_{MIN} to T_{MAX}	$I_{SINK} = 15 \text{ mA}$		300	500		300	500	mV
$V_{CC} - V_{OH}$ T_{MIN} to T_{MAX}	$I_{SOURCE} = 15 \text{ mA}$		800	1500		800	1500	mV
Operating Output Current T_{MIN} to T_{MAX}		20			20			mA
Capacitive Load Drive		15	350		15	350		mA
POWER SUPPLY								
Quiescent Current, T_{MIN} to T_{MAX}			1.4	1.8		1.4	1.8	mA
Power Supply Rejection T_{MIN} to T_{MAX}	$V_{SY} = \pm 5 \text{ V to } \pm 15 \text{ V}$	70	80		70	80		dB
		70			70			dB

¹ This is a functional specification. Amplifier bandwidth decreases when the input common-mode voltage is driven in the range $(V_+ - 1 \text{ V})$ to V_+ . Common-mode error voltage is typically less than 5 mV with the common-mode voltage set at 1 V below the positive supply.

² $V_{OL} - V_{EE}$ is defined as the difference between the lowest possible output voltage (V_{OL}) and the negative voltage supply rail (V_{EE}). $V_{CC} - V_{OH}$ is defined as the difference between the highest possible output voltage (V_{OH}) and the positive supply voltage (V_{CC}).

ABSOLUTE MAXIMUM RATINGS

Table 4.

Parameter	Rating
Supply Voltage	$\pm 18\text{ V}$
Internal Power Dissipation	
8-Lead PDIP (N)	Observe derating curves
8-Lead SOIC_N (R)	Observe derating curves
8-Lead MSOP (RM)	Observe derating curves
Input Voltage ¹	((V+) + 0.2 V) to ((V-) - 20 V)
Output Short-Circuit Duration	Indefinite
Differential Input Voltage	$\pm 30\text{ V}$
Storage Temperature Range (N)	-65°C to +125°C
Storage Temperature Range (R, RM)	-65°C to +150°C
Operating Temperature Range	
A Grade and B Grade	-40°C to +85°C
Lead Temperature (Soldering, 60 sec)	260°C

¹ See the Input Characteristics section.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

THERMAL RESISTANCE

θ_{JA} is specified for the worst case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 5. Thermal Resistance

Package Type	θ_{JA}	Unit
8-lead PDIP (N)	90	°C/W
8-lead SOIC_N (R)	160	°C/W
8-lead MSOP (RM)	190	°C/W

MAXIMUM POWER DISSIPATION

The maximum power that can be safely dissipated by the AD822 is limited by the associated rise in junction temperature. For plastic packages, the maximum safe junction temperature is 145°C. If these maximums are exceeded momentarily, proper circuit operation is restored as soon as the die temperature is reduced. Leaving the device in the overheated condition for an extended period can result in device burnout. To ensure proper operation, it is important to observe the derating curves shown in Figure 27.

While the AD822 is internally short-circuit protected, this may not be sufficient to guarantee that the maximum junction temperature is not exceeded under all conditions. With power supplies $\pm 12\text{ V}$ or less at an ambient temperature of 25°C or less, if the output node is shorted to a supply rail, then the amplifier is not destroyed, even if this condition persists for an extended period.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

TYPICAL PERFORMANCE CHARACTERISTICS

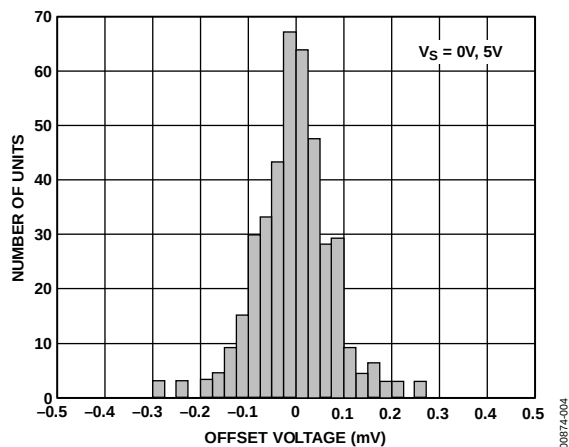


Figure 4. Typical Distribution of Offset Voltage (390 Units)

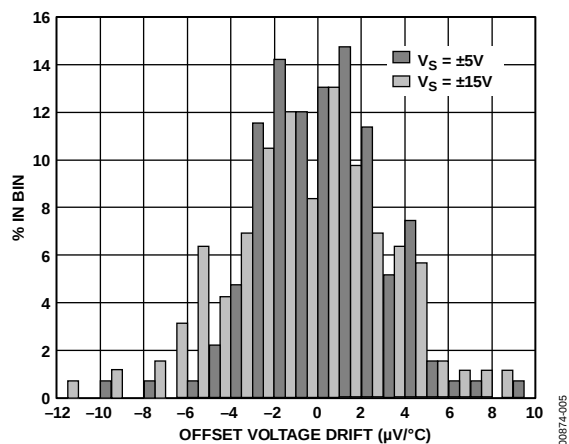


Figure 5. Typical Distribution of Offset Voltage Drift (100 Units)

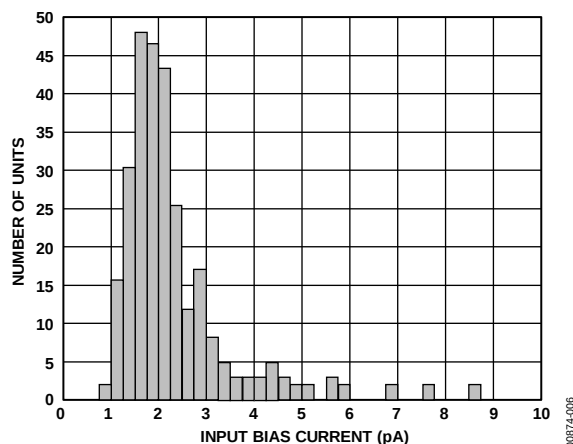
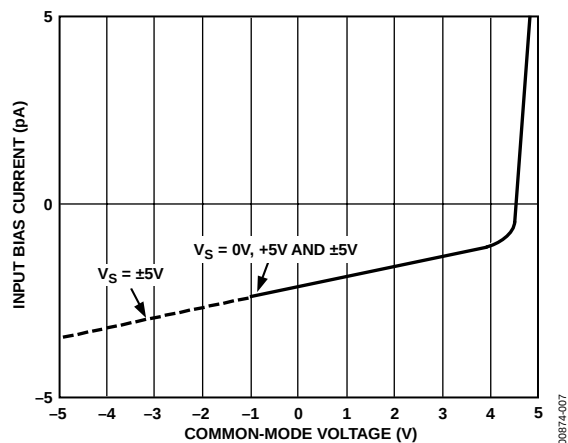
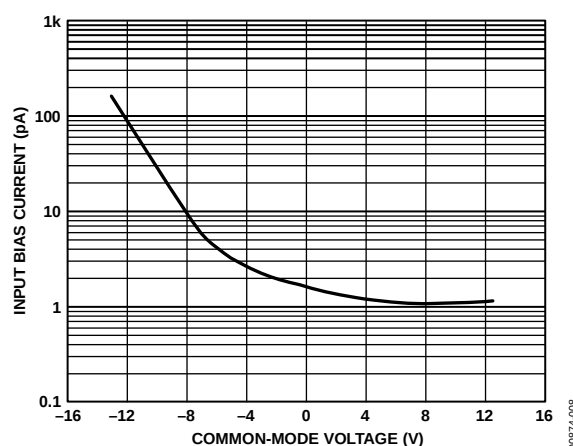
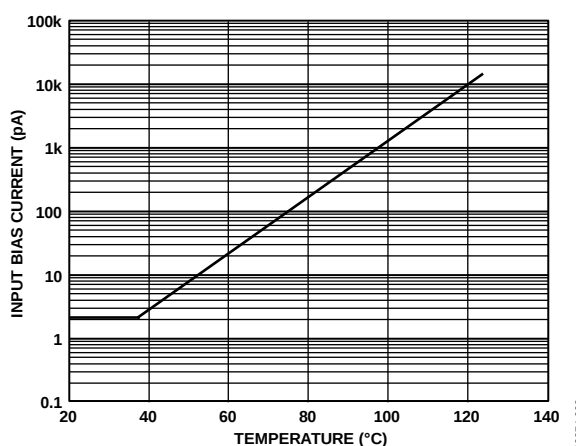


Figure 6. Typical Distribution of Input Bias Current (213 Units)

Figure 7. Input Bias Current vs. Common-Mode Voltage; $V_S = 5\text{ V}$, 0 V , and $V_S = \pm 5\text{ V}$ Figure 8. Input Bias Current vs. Common-Mode Voltage; $V_S = \pm 15\text{ V}$ Figure 9. Input Bias Current vs. Temperature; $V_S = 5\text{ V}$, $V_{CM} = 0\text{ V}$

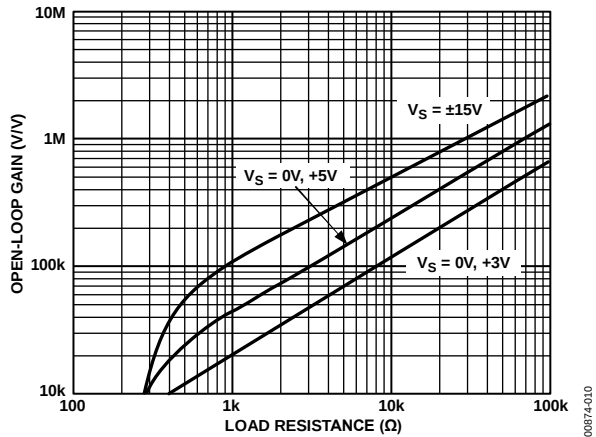


Figure 10. Open-Loop Gain vs. Load Resistance

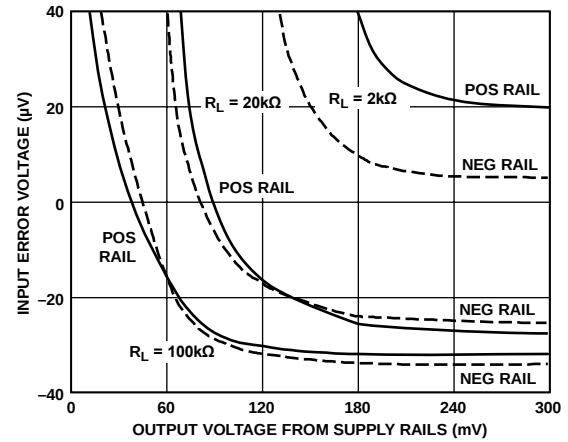
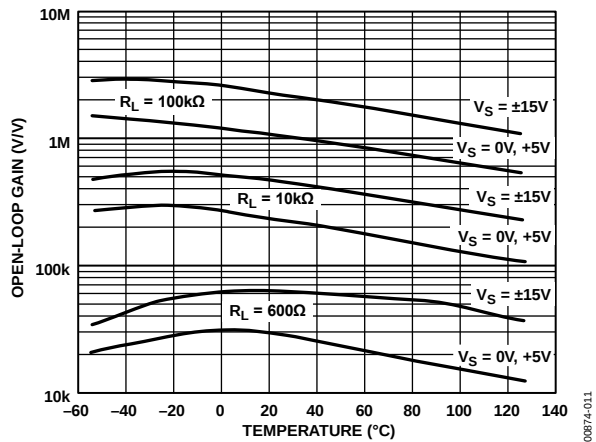
Figure 13. Input Error Voltage with Output Voltage Within 300 mV of Either Supply Rail for Various Resistive Loads; $V_S = \pm 5\text{ V}$ 

Figure 11. Open-Loop Gain vs. Temperature

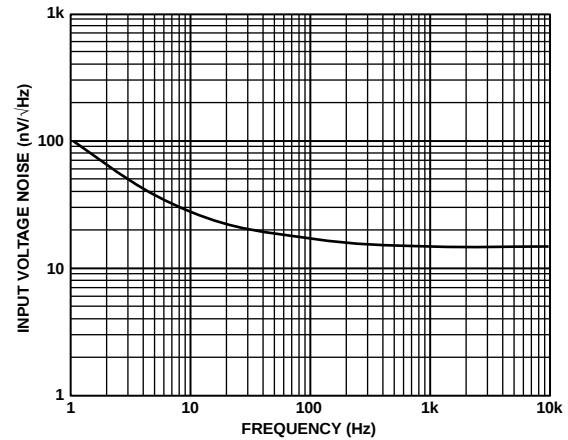


Figure 14. Input Voltage Noise vs. Frequency

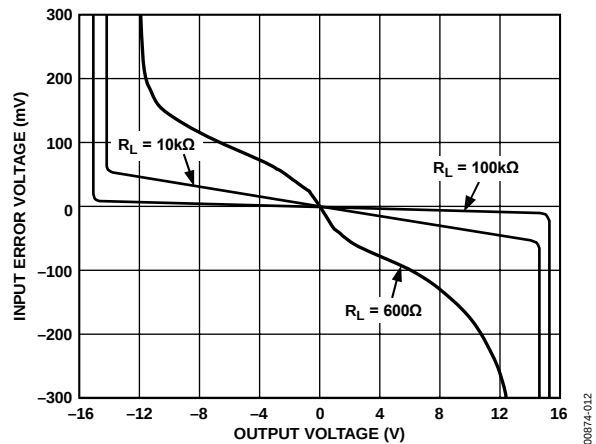


Figure 12. Input Error Voltage vs. Output Voltage for Resistive Loads

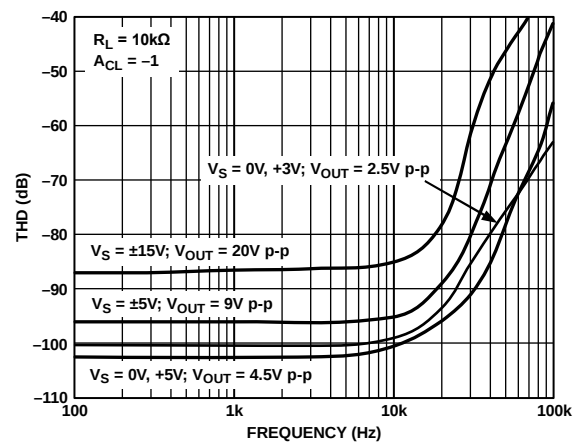


Figure 15. THD vs. Frequency

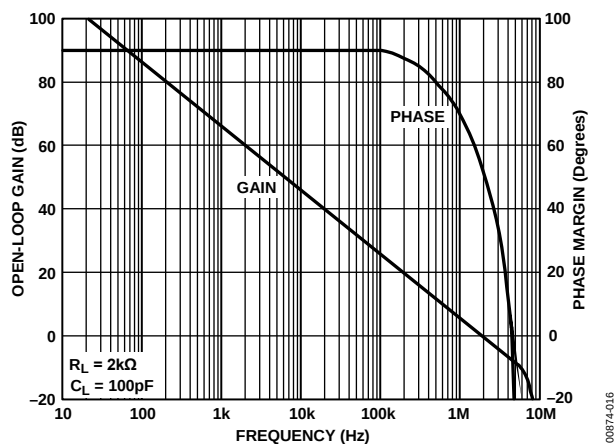


Figure 16. Open-Loop Gain and Phase Margin vs. Frequency

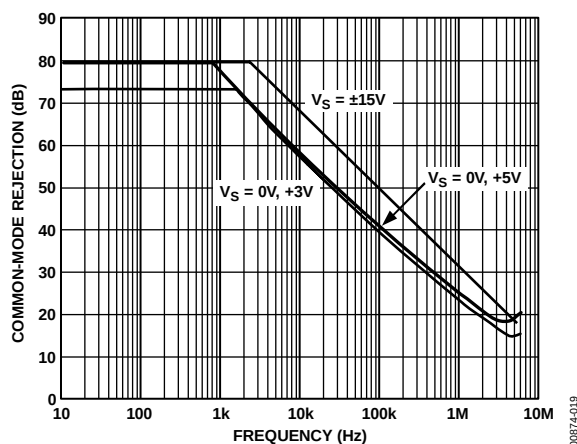


Figure 19. Common-Mode Rejection vs. Frequency

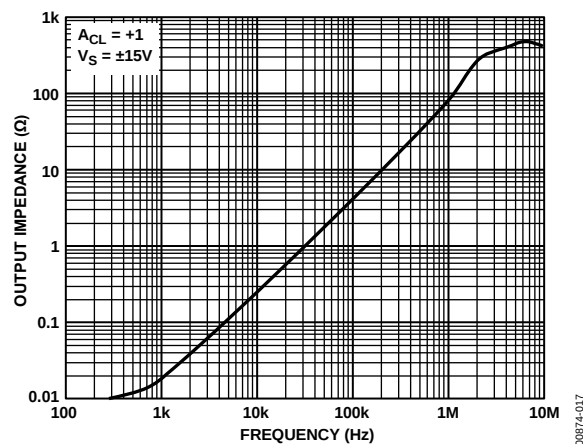


Figure 17. Output Impedance vs. Frequency

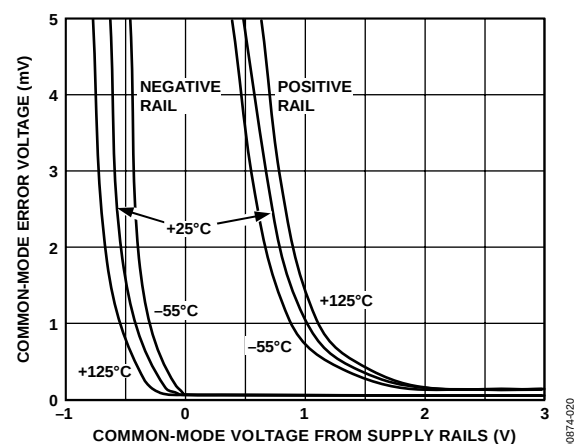
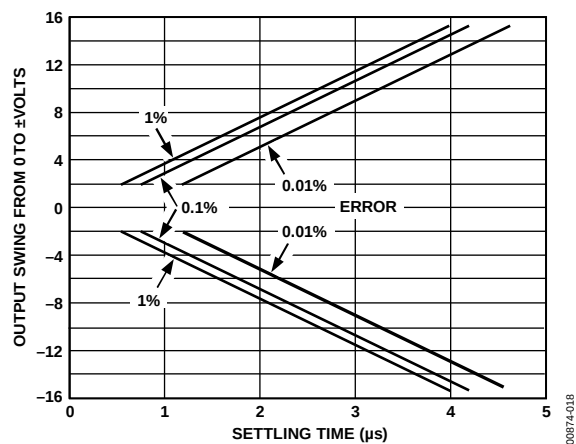
Figure 20. Absolute Common-Mode Error vs. Common-Mode Voltage from Supply Rails ($V_S - V_{CM}$)

Figure 18. Output Swing and Error vs. Settling Time

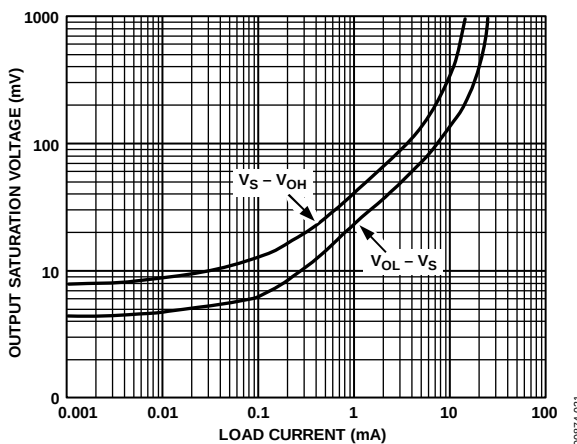


Figure 21. Output Saturation Voltage vs. Load Current

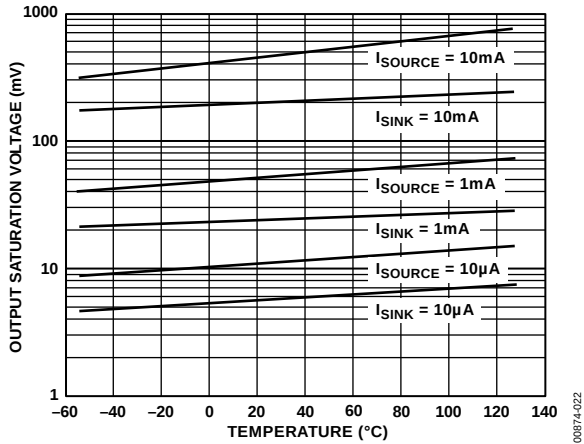


Figure 22. Output Saturation Voltage vs. Temperature

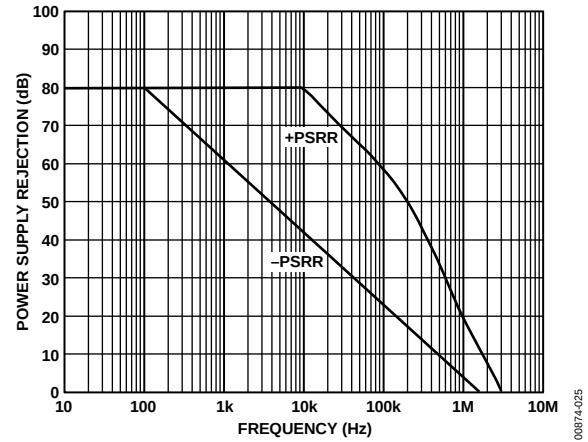


Figure 25. Power Supply Rejection vs. Frequency

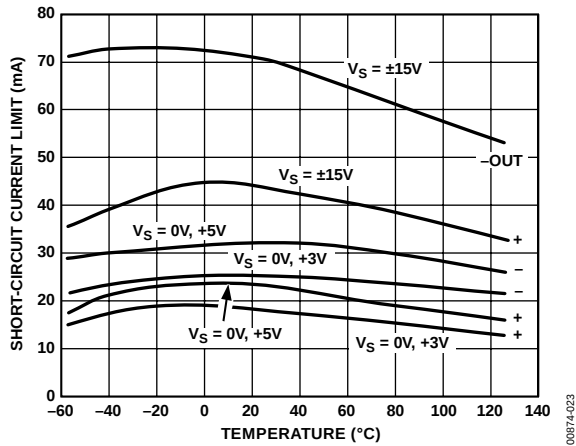


Figure 23. Short-Circuit Current Limit vs. Temperature

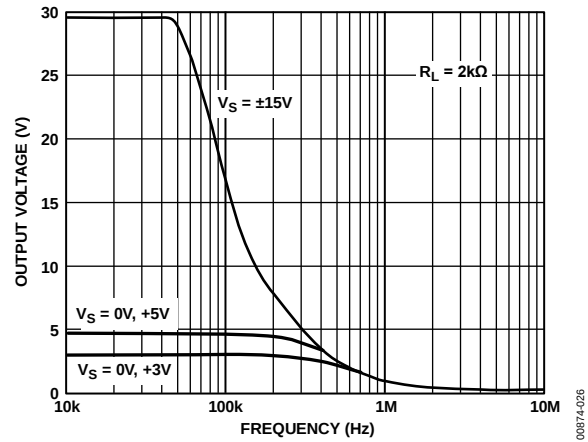


Figure 26. Large Signal Frequency Response

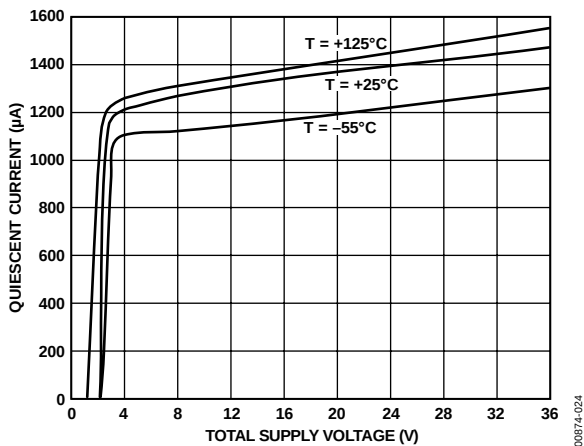


Figure 24. Quiescent Current vs. Supply Voltage vs. Temperature

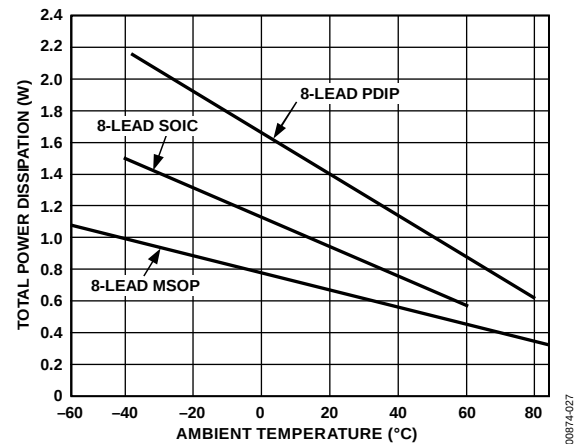


Figure 27. Maximum Power Dissipation vs. Temperature for Packages

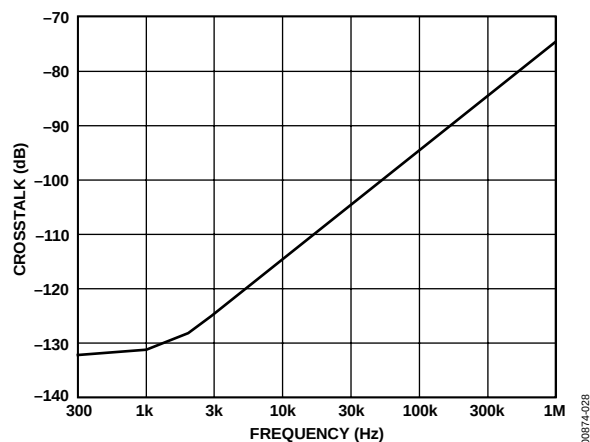


Figure 28. Crosstalk vs. Frequency

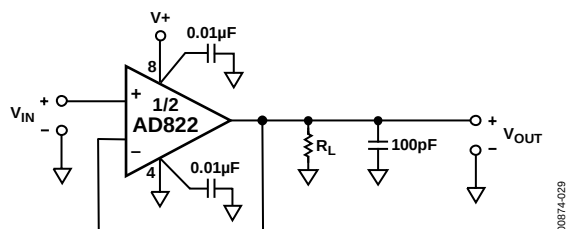
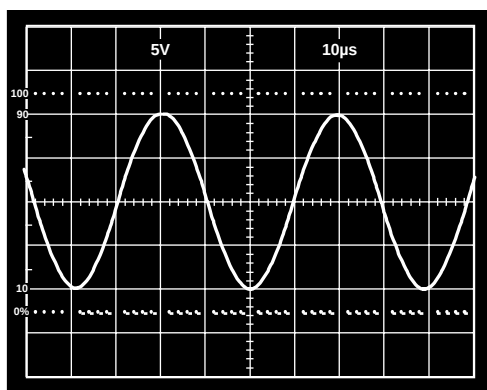
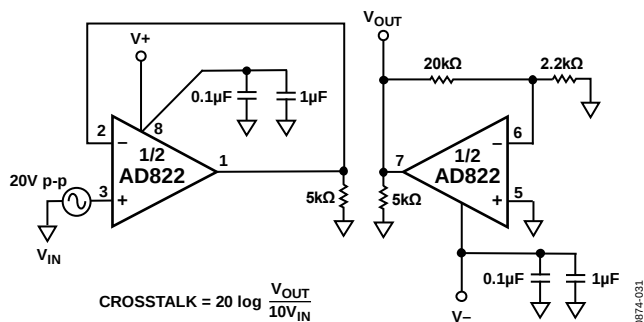


Figure 29. Unity-Gain Follower

Figure 30. 20 V p-p, 25 kHz Sine Wave Input; Unity-Gain Follower; $V_S = \pm 15$ V, $R_L = 600 \Omega$ 

$$\text{CROSSTALK} = 20 \log \frac{V_{\text{OUT}}}{10V_{\text{IN}}}$$

Figure 31. Crosstalk Test Circuit

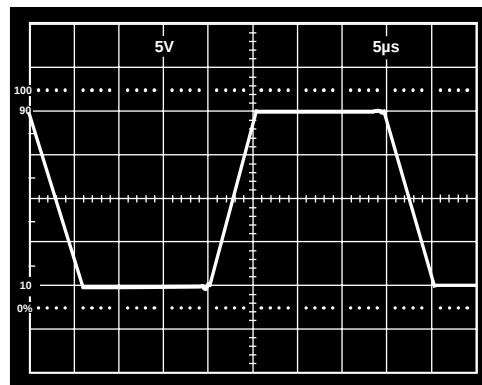
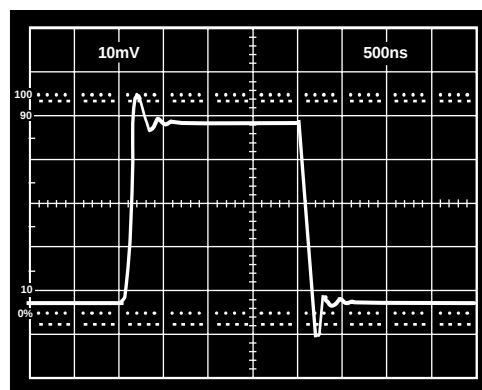
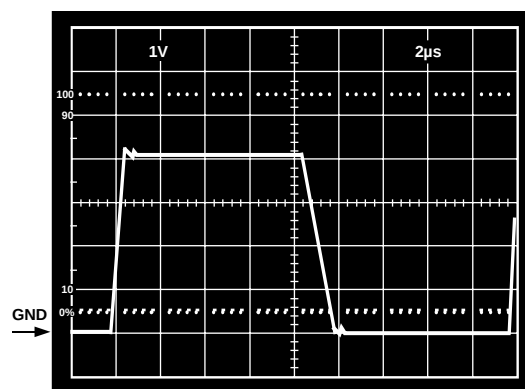
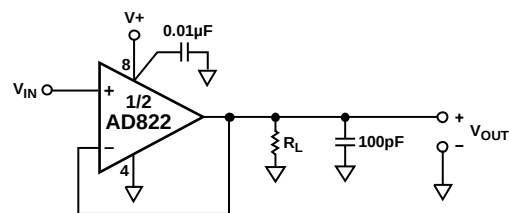
Figure 32. Large Signal Response Unity-Gain Follower; $V_S = \pm 15$ V, $R_L = 10 \text{ k}\Omega$ Figure 33. Small Signal Response Unity-Gain Follower; $V_S = \pm 15$ V, $R_L = 10 \text{ k}\Omega$ Figure 34. $V_S = 5$ V, 0 V; Unity-Gain Follower Response to 0 V to 4 V Step

Figure 35. Unity-Gain Follower

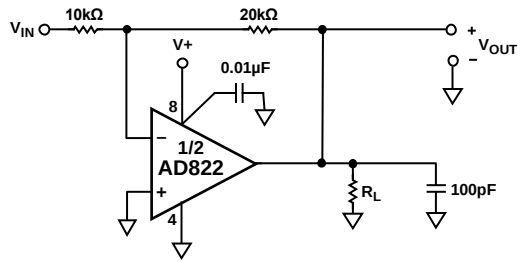
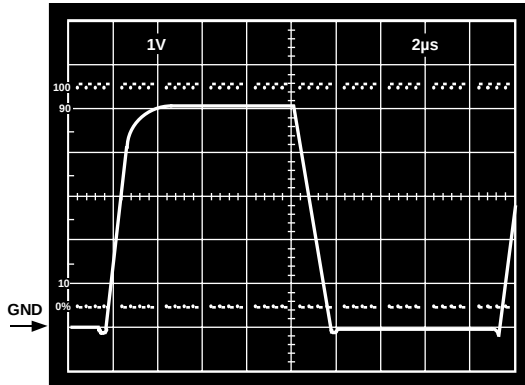
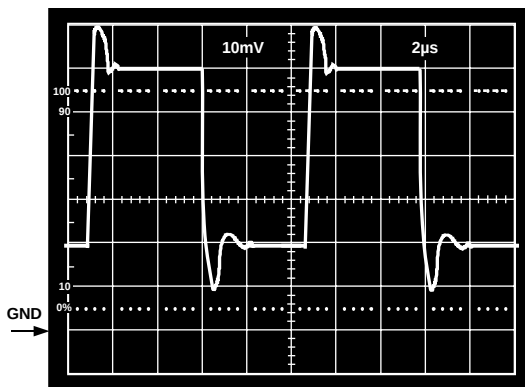
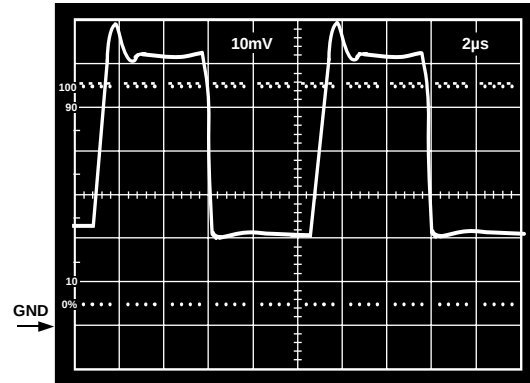
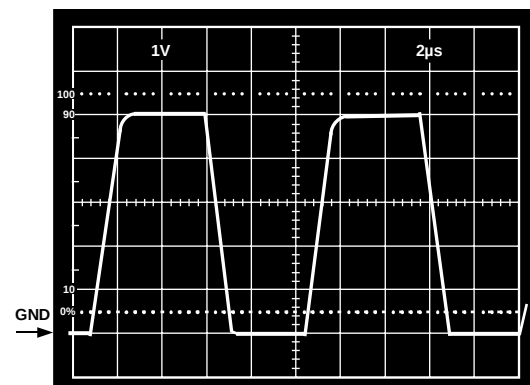
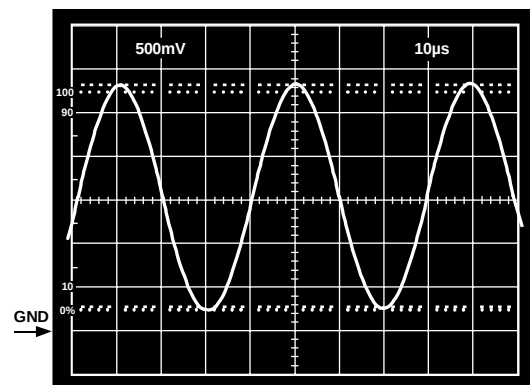
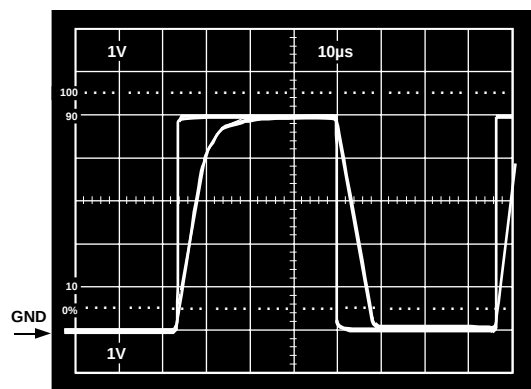
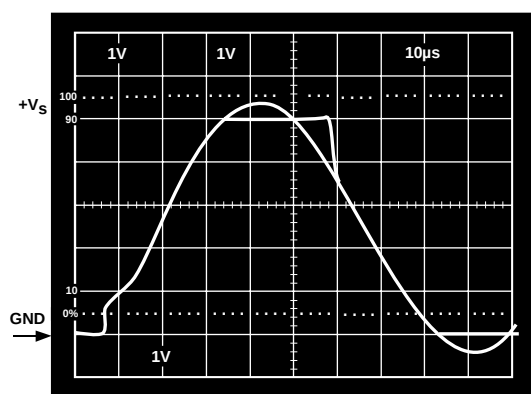


Figure 36. Gain of 2 Inverter

Figure 37. $V_S = 5\text{ V}$, 0 V ; Unity-Gain Follower Response to 0 V to 5 V StepFigure 38. $V_S = 5\text{ V}$, 0 V ; Unity-Gain Follower Response to 40 mV Step, Centered 40 mV above Ground, $R_L = 10\text{ k}\Omega$ Figure 39. $V_S = 5\text{ V}$, 0 V ; Gain of 2 Inverter Response to 20 mV Step, Centered 20 mV Below Ground, $R_L = 10\text{ k}\Omega$ Figure 40. $V_S = 5\text{ V}$, 0 V ; Gain of 2 Inverter Response to 2.5 V Step, Centered -1.25 V Below Ground, $R_L = 10\text{ k}\Omega$ Figure 41. $V_S = 3\text{ V}$, 0 V ; Gain of 2 Inverter, $V_{IN} = 1.25\text{ V}$, 25 kHz , Sine Wave Centered at -0.75 V , $R_L = 600\text{ }\Omega$



(a)



(b)

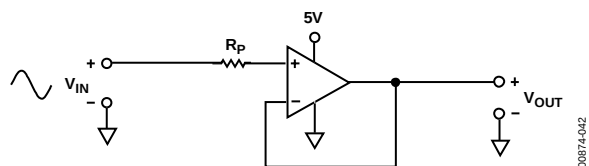


Figure 42. (a) Response with $R_P = 0$; V_{IN} from 0 V to $+V_S$
 (b) $V_{IN} = 0$ V to $+V_S + 200$ mV
 $V_{OUT} = 0$ V to $+V_S$
 $R_P = 49.9$ k Ω

APPLICATIONS INFORMATION

INPUT CHARACTERISTICS

In the [AD822](#), N-channel JFETs are used to provide a low offset, low noise, high impedance input stage. Minimum input common-mode voltage extends from 0.2 V below $-V_S$ to 1 V less than $+V_S$. Driving the input voltage closer to the positive rail causes a loss of amplifier bandwidth (as can be seen by comparing the large signal responses shown in Figure 34 and Figure 37) and increased common-mode voltage error as illustrated in Figure 20.

The [AD822](#) does not exhibit phase reversal for input voltages up to and including $+V_S$. Figure 42 shows the response of an [AD822](#) voltage follower to a 0 V to 5 V ($+V_S$) square wave input. The input and output are superimposed. The output tracks the input up to $+V_S$ without phase reversal. The reduced bandwidth above a 4 V input causes the rounding of the output waveform. For input voltages greater than $+V_S$, a resistor in series with the [AD822](#) noninverting input prevents phase reversal, at the expense of greater input voltage noise. This is illustrated in Figure 42.

Because the input stage uses N-channel JFETs, input current during normal operation is negative; the current flows out from the input terminals. If the input voltage is driven more positive than $+V_S - 0.4$ V, then the input current reverses direction as internal device junctions become forward biased. This is illustrated in Figure 7.

A current-limiting resistor should be used in series with the input of the [AD822](#) if there is a possibility of the input voltage exceeding the positive supply by more than 300 mV, or if an input voltage is applied to the [AD822](#) when $+V_S$ or $-V_S = 0$ V. The amplifier is damaged if left in that condition for more than 10 seconds. A 1 k Ω resistor allows the amplifier to withstand up to 10 V of continuous overvoltage and increases the input voltage noise by a negligible amount.

Input voltages less than $-V_S$ are different. The amplifier can safely withstand input voltages 20 V below the negative supply voltage if the total voltage from the positive supply to the input terminal is less than 36 V. In addition, the input stage typically maintains picoampere (pA) level input currents across that input voltage range.

The [AD822](#) is designed for 13 nV/ $\sqrt{\text{Hz}}$ wideband input voltage noise and maintains low noise performance to low frequencies (refer to Figure 14). This noise performance, along with the [AD822](#) low input current and current noise, means that the [AD822](#) contributes negligible noise for applications with source resistances greater than 10 k Ω and signal bandwidths greater than 1 kHz. This is illustrated in Figure 43.

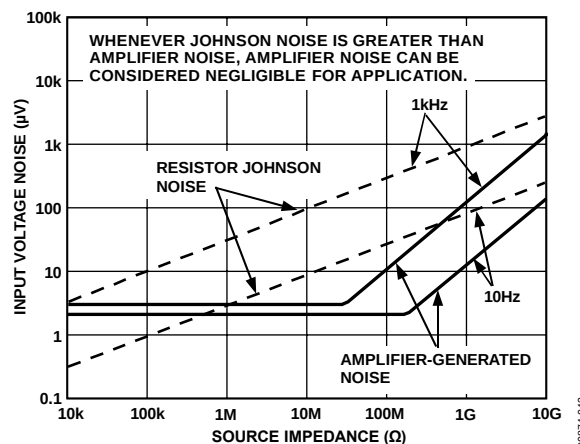


Figure 43. Total Noise vs. Source Impedance

OUTPUT CHARACTERISTICS

The [AD822](#) unique bipolar rail-to-rail output stage swings within 5 mV of the negative supply and 10 mV of the positive supply with no external resistive load. The approximate output saturation resistance of the [AD822](#) is 40 Ω sourcing and 20 Ω sinking, which can be used to estimate output saturation voltage when driving heavier current loads. For instance, when sourcing 5 mA, the saturation voltage to the positive supply rail is 200 mV; when sinking 5 mA, the saturation voltage to the negative rail is 100 mV.

The open-loop gain characteristic of the amplifier changes as a function of resistive load, as shown in Figure 10 to Figure 13. For load resistances over 20 k Ω , the [AD822](#) input error voltage is virtually unchanged until the output voltage is driven to 180 mV of either supply.

If the [AD822](#) output is overdriven so that either of the output devices are saturated, the amplifier recovers within 2 μs of the input returning to the linear operating region of the amplifier.

Direct capacitive loads interact with the effective output impedance of the amplifier to form an additional pole in the amplifier feedback loop, which can cause excessive peaking on the pulse response or loss of stability. The worst case occurs when the amplifier is used as a unity-gain follower. Figure 44 shows the [AD822](#) pulse response as a unity-gain follower driving 350 pF. This amount of overshoot indicates approximately 20° of phase margin—the system is stable, but nearing the edge. Configurations with less loop gain, and as a result less loop bandwidth, are much less sensitive to capacitance load effects.

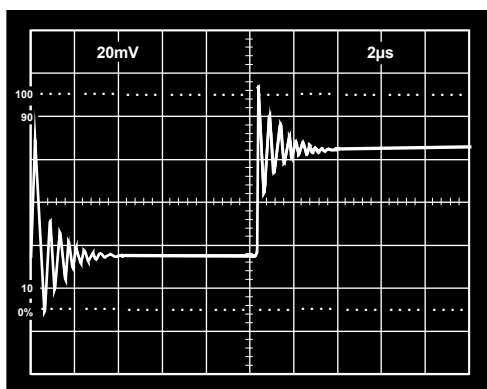


Figure 44. Small Signal Response of AD822 as Unity-Gain Follower Driving 350 pF

Figure 45 is a plot of noise gain vs. capacitive load that results in a 20° phase margin for the [AD822](#). Noise gain is the inverse of the feedback attenuation factor provided by the feedback network in use.

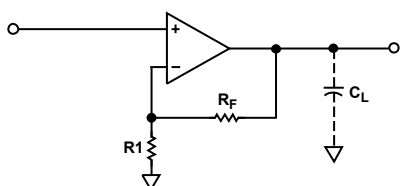
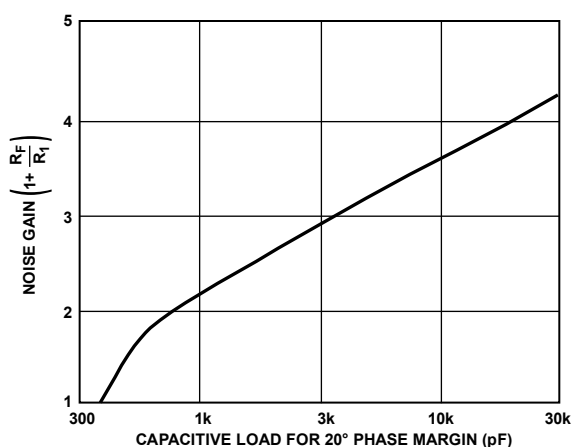


Figure 45. Noise Gain vs. Capacitive Load Tolerance

Figure 46 shows a method for extending capacitance load drive capability for a unity-gain follower. With these component values, the circuit drives 5000 pF with a 10% overshoot.

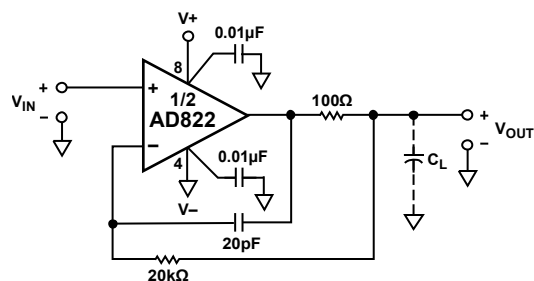


Figure 46. Extending Unity-Gain Follower Capacitive Load Capability Beyond 350 pF

SINGLE-SUPPLY VOLTAGE TO FREQUENCY CONVERTER

The circuit shown in Figure 47 uses the [AD822](#) to drive a low power timer that produces a stable pulse of width t_i . The positive going output pulse is integrated by R1 and C1 and used as one input to the [AD822](#) that is connected as a differential integrator. The other input (nonloading) is the unknown voltage, V_{IN} . The [AD822](#) output drives the timer trigger input, closing the overall feedback loop.

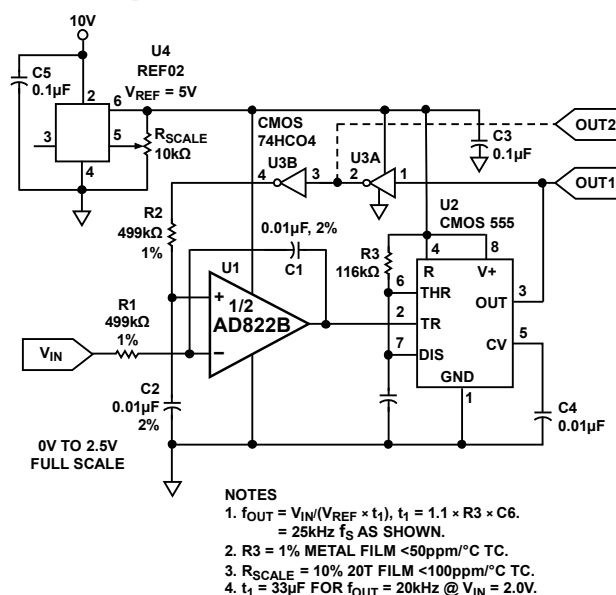


Figure 47. Single-Supply Voltage to Frequency Converter

Typical AD822 bias currents of 2 pA allow M Ω range source impedances with negligible dc errors. Linearity errors on the order of 0.01% full scale can be achieved with this circuit. This performance is obtained with a 5 V single supply that delivers less than 1 mA to the entire circuit.

SINGLE-SUPPLY PROGRAMMABLE GAIN INSTRUMENTATION AMPLIFIER

The AD822 can be configured as a single-supply instrumentation amplifier that is able to operate from single supplies down to 3 V or dual supplies up to ± 15 V. Using only one AD822 rather than three separate op amps, this circuit is cost and power efficient. The 2 pA bias currents of the AD822 FET inputs minimize offset errors caused by high, unbalanced source impedances.

An array of precision thin film resistors sets the in-amp gain to be either 10 or 100. These resistors are laser trimmed to ratio match to 0.01% and have a maximum differential temperature coefficient of 5 ppm/ $^{\circ}$ C.

Table 6. In-Amp Performance

Parameters	$V_S = 3\text{ V}, 0\text{ V}$	$V_S = \pm 5\text{ V}$
CMRR	74 dB	80 dB
Common-Mode Voltage Range	-0.2 V to +2 V	-5.2 V to +4 V
3 dB BW		
G = 10	180 kHz	180 kHz
G = 100	18 kHz	18 kHz
t_{SETTLING}		
2 V Step	2 μ s	
5 V Step		5 μ s
Noise @ f = 1 kHz		
G = 10	270 nV/ $\sqrt{\text{Hz}}$	270 nV/ $\sqrt{\text{Hz}}$
G = 100	2.2 μ V/ $\sqrt{\text{Hz}}$	2.2 μ V/ $\sqrt{\text{Hz}}$
I_{SUPPLY} (Total)	1.10 mA	1.15 mA

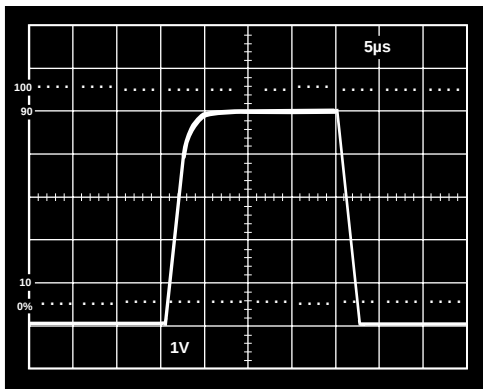


Figure 48. Pulse Response of In-Amp to a 500 mV p-p Input Signal;
 $V_S = 5\text{ V}, 0\text{ V}$; Gain = 0

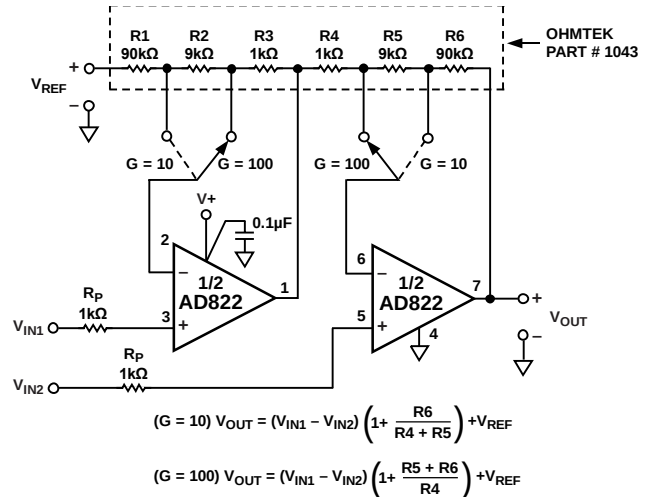


Figure 49. A Single-Supply Programmable Instrumentation Amplifier

LOW DROPOUT BIPOLAR BRIDGE DRIVER

The AD822 can be used for driving a 350 Ω Wheatstone bridge. Figure 50 shows one half of the AD822 being used to buffer the AD589, a 1.235 V low power reference. The output of 4.5 V can be used to drive an analog-to-digital converter (ADC) front end. The other half of the AD822 is configured as a unity-gain inverter and generates the other bridge input of -4.5 V. Resistor R1 and Resistor R2 provide a constant current for bridge excitation. The AD620 low power instrumentation amplifier is used to condition the differential output voltage of the bridge. The gain of the AD620 is programmed using an external resistor (R_G) and determined by

$$G = \frac{49.9\text{ k}\Omega}{R_G} + 1$$

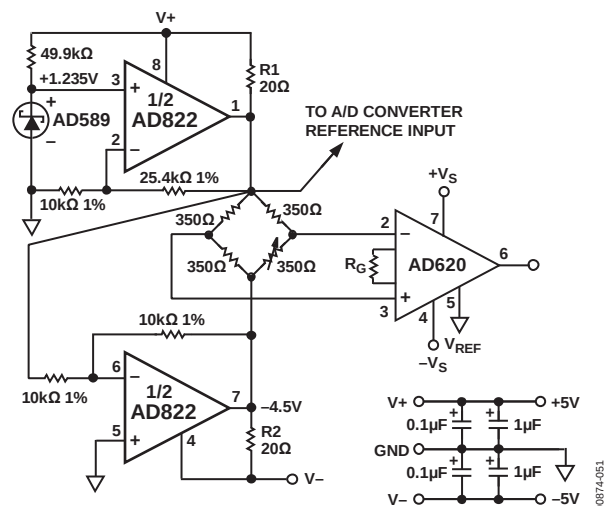
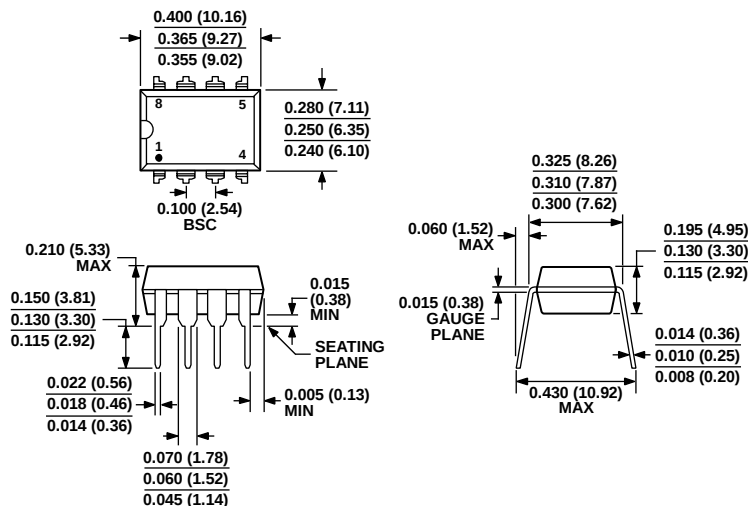


Figure 50. Low Dropout Bipolar Bridge Driver

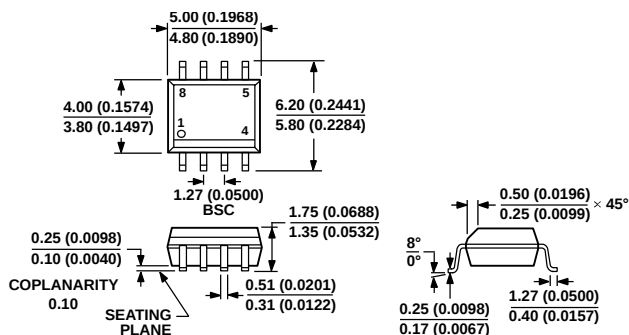
OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MS-001
CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN. CORNER LEADS MAY BE CONFIGURED AS WHOLE OR HALF LEADS.

Figure 51. 8-Lead Plastic Dual In-Line Package [PDIP]
Narrow Body
(N-8)

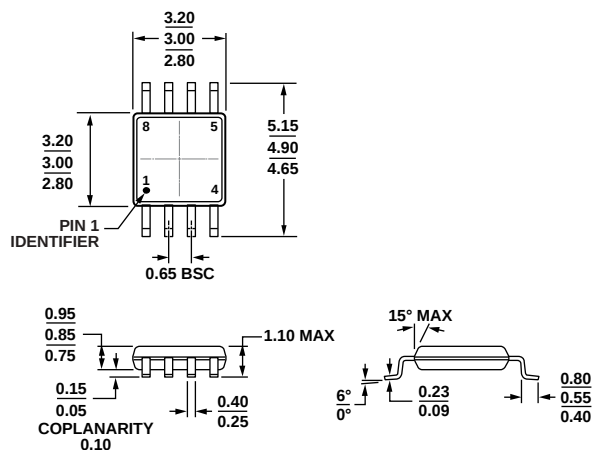
Dimensions shown in inches and (millimeters)



COMPLIANT TO JEDEC STANDARDS MS-012-AA
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 52. 8-Lead Standard Small Outline Package [SOIC_N]
Narrow Body
(R-8)

Dimensions shown in millimeters and (inches)



COMPLIANT TO JEDEC STANDARDS MO-187-AA

Figure 53. 8-Lead Mini Small Outline Package [MSOP]
(RM-8)

Dimensions shown in millimeters

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option	Branding
AD822AN	−40°C to +85°C	8-Lead PDIP	N-8	#B4A #B4A
AD822ANZ	−40°C to +85°C	8-Lead PDIP	N-8	
AD822AR	−40°C to +85°C	8-Lead SOIC_N	R-8	
AD822AR-REEL	−40°C to +85°C	8-Lead SOIC_N	R-8	
AD822AR-REEL7	−40°C to +85°C	8-Lead SOIC_N	R-8	
AD822ARZ	−40°C to +85°C	8-Lead SOIC_N	R-8	
AD822ARZ-REEL	−40°C to +85°C	8-Lead SOIC_N	R-8	
AD822ARZ-REEL7	−40°C to +85°C	8-Lead SOIC_N	R-8	
AD822ARMZ	−40°C to +85°C	8-Lead MSOP	RM-8	
AD822ARMZ-REEL	−40°C to +85°C	8-Lead MSOP	RM-8	
AD822BR	−40°C to +85°C	8-Lead SOIC_N	R-8	
AD822BR-REEL	−40°C to +85°C	8-Lead SOIC_N	R-8	
AD822BR-REEL7	−40°C to +85°C	8-Lead SOIC_N	R-8	
AD822BRZ	−40°C to +85°C	8-Lead SOIC_N	R-8	
AD822BRZ-REEL	−40°C to +85°C	8-Lead SOIC_N	R-8	
AD822BRZ-REEL7	−40°C to +85°C	8-Lead SOIC_N	R-8	

¹ Z = RoHS Compliant Part, # denotes RoHS-compliant product may be top or bottom marked.

SPICE model is available at www.analog.com.

NOTES

NOTES